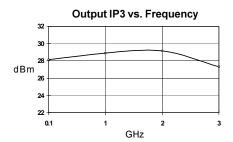


Product Description

Sirenza Microdevices' SCA-16 is a high performance Gallium Arsenide Heterojunction Bipolar Transistor MMIC Amplifier. A Darlington configuration is utilized for broadband performance up to 3 GHz. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. Typical IP3 at 50mA is +28dBm.

These unconditionally stable amplifiers provides 15dB of gain and +14.5dBm of 1dB compressed power and requires only a single positive voltage supply. Only 2 DC-blocking capacitors, a bias resistor and an optional inductor are needed for operation.



SCA-16

DC-3 GHz, Cascadable **GaAs HBT MMIC Amplifier**



Product Features

- High Output IP3: +28dBm
- Flat Gain: +/- 0.7dB Over Full Band
- Cascadable 50 Ohm: 1.5:1 VSWR
- Patented GaAsHBT Technology
- Operates From Single Supply
- Low Thermal Resistance Package

Applications

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS
- IF Amplifier
- · Wireless Data. Satellite

Symbol	Parameter	Units	Frequency	Min.	Тур.	Max.
G _P	Small Signal Power Gain	dB dB dB	850 MHz 1950 MHz 2400 MHz	14.4	16.0 15.5 15.0	17.6
G_{F}	Gain Flatness	dB	0.1-2.0 GHz		+/- 0.7	
P _{1dB}	Output Power at 1dB Compression	dBm	1950 MHz		14.5	
OIP ₃	Output Third Order Intercept Point	dBm	1950 MHz		28.0	
NF	Noise Figure	dB	1950 MHz		5.5	
VSWR	Input / Output	-	0.1-3.0 GHz		1.5:1	
ISOL	Reverse Isolation	dB	0.1-3.0 GHz		20	
V _D	Device Operating Voltage	V		3.3	3.8	4.3
I _D	Device Operating Current	mA		45	50	55
dG/dT	Device Gain Temperature Coefficient	dB/°C			-0.0018	
R _{TH} , j-I	Thermal Resistance (junction to lead)	°C/W			510	

Test Conditions:

= 82 Ohms

 $I_D = 50 \text{ mA Typ.}$

OIP, Tone Spacing = 1 MHz, Pout per tone = 0 dBm $Z_s = \overline{Z_l} = 50 \text{ Ohms}$

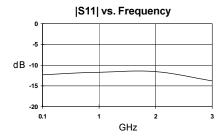
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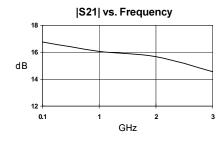
Phone: (800) SMI-MMIC

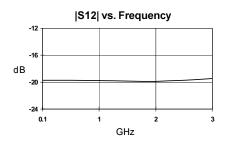


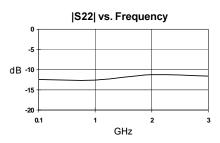
SCA-16 DC-3 GHz Cascadable MMIC Amplifier

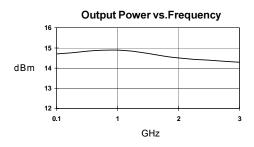
Typical Performance at 25 $^{\circ}$ C (Vds = 3.8V, Ids = 50mA)











Typical S-Parameters Vds = 3.8V, Id = 50mA

Freq GHz	S11	S11 Ang	S21	S21 Ang	S12	S12 Ang	S22	S22 Ang
.100	0.247	125	6.531	148	0.108	-42	0.212	124
.500	0.241	117	6.606	136	0.103	-31	0.206	117
.900	0.256	70	6.397	103	0.102	-55	0.228	71
1.00	0.260	58	6.362	93	0.103	-61	0.235	59
1.50	0.272	3	6.174	52	0.102	-93	0.260	3
2.00	0.265	-50	6.078	10	0.101	-122	0.273	-52
2.50	0.240	-104	5.638	-32	0.104	-153	0.274	-109
3.00	0.204	-160	5.343	-70	0.106	172	0.264	-167

(S-Parameters include the effects of two 1.0 mil diameter bond wires, each 20 mils long, connected to the gate and drain pads on the die)



SCA-16 DC-3 GHz Cascadable MMIC Amplifier

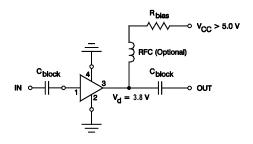
Absolute Maximum Ratings

Parameter	Absolute Limit		
Max. Device Current (I _D)	75 mA		
Max. Device Voltage (V _D)	6 V		
Max. RF Input Power	+20 dBm		
Max. Junction Temp. (T _J)	+150°C		
Operating Temp. Range (T _L)	-40°C to +85°C		
Max. Storage Temp.	+150°C		

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.

Bias Conditions should also satisfy the following expression: $I_pV_p < (T_J - T_I) / R_{TH}$, j-I

Typical Biasing Configuration



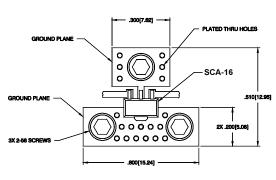
Recommended Bias Resistor Values						
Supply Voltage (Vs)	5V	7.5V	9V	12V	15V	20V
Rbias (Ohms)	20	70	100	160	220	320

Mounting Instructions

The data shown was taken on a 31mil thick FR-4 board with 1 ounce of copper on both sides.

The board was mounted to a baseplate with 3 screws as shown. The screws bring the top side copper temperature to the same value as the baseplate.

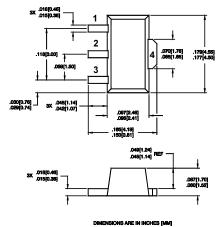
- 1. Use 1 or 2 ounce copper, if possible.
- 2. Solder the copper pad on the backside of the device package to the ground plane.
- 3. Use a large ground pad area with many plated throughholes as shown.
- 4. If possible, use at least one screw no more than 0.2 inch from the device package to provide a low thermal resistance path to the baseplate of the package.
- 5. Thermal resistance from ground lead to screws is 2 deg. C/W.



DIMENSIONS ARE IN INCHES [MM]

Pin Designation				
1	RF in			
2	GND			
3	RF out and Bias			
4	GND			

Outline Drawing



Pin assignments shown for reference only, not marked on part

EDS-102425 Rev A